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PMP23470 REV D Bill of Materials

Designator	Quantity	Value	PartNumber	Manufacturer	Description	PackageReference
C16	1	47pF	885012005044	Wurth Elektronik	CAP, CERM, 47 pF, 50 V, +/- 5%, C0G/NP0, 0402	0402
C17	1	120pF	GRM1555C1H121JA01D	MuRata	CAP, CERM, 120 pF, 50 V, +/- 5%, C0G/NP0, 0402	0402
C24	1	150pF	885012005062	Wurth Elektronik	CAP, CERM, 150 pF, 50 V,+/- 5%, C0G/NP0, 0402	0402
C21	1	0.1uF	885012205037	Wurth Elektronik	CAP, CERM, 0.1 uF, 16 V, +/- 10%, X7R, 0402	0402
C20	1	0.047uF	C1608X7R1H473K080AA	TDK	CAP, CERM, 0.047 uF, 50 V, +/- 10%, X7R, 0603	0603
C9, C14, C23	3	0.1uF	C0603C104K5RACTU	Kemet	CAP, CERM, 0.1 uF, 50 V, +/- 10%, X7R, 0603	0603
C11, C15, C18	3	1uF	C0603C105K3RACTU	Kemet	CAP, CERM, 1 uF, 25 V, +/- 10%, X7R, 0603	0603
C10, C13	2	100pF	GRM21A5C2E101JW01D	MuRata	CAP, CERM, 100 pF, 250 V, +/- 5%, C0G/NP0, 0805	0805
C3, C5	2	0.1uF	885012207128	Wurth Elektronik	CAP, CERM, 0.1 µF, 100 V,+/- 10%, X7R, 0805	0805
C4	1	2.2uF	C1210C225K1RAC7800	Kemet	CAP, CERM, 2.2 uF, 100 V, +/- 10%, X7R, 1210	1210
C7, C8, C26	3	4.7uF	C1210C475K5RACAUTO	Kemet	CAP, CERM, 4.7 µF, 50 V,+/- 10%, X7R, AEC-Q200 Grade 1, 1210	1210
C1, C12	2	4700pF	1812GC472KA1	AVX	CAP, CERM, 4700 pF, 2000 V, +/- 10%, X7R, 1812	1812
C2	1	22uF	EEE-FK2A220P	Panasonic	CAP, AL, 22 uF, 100 V, +/- 20%, 1.3 ohm, AEC-Q200 Grade 2, SMD	SMT Radial F
D1	1	200V	ES2DA-13-F	Diodes Inc.	Diode, Superfast Rectifier, 200 V, 2 A, SMA	SMA
D2	1	200V	PDU620-13	Diodes Inc.	Diode, Ultrafast, 200 V, 6 A, PowerDI5	PowerDI5
D3	1	100V	1N4148W-7-F	Diodes Inc.	Diode, Ultrafast, 100 V, 0.15 A, SOD-123	SOD-123
D4	1	20V	MMSZ5250BS-7-F	Diodes Inc.	Diode, Zener, 20 V, 200 mW, SOD-323	SOD-323
D5, D8, D9	3	100V	BAS516,115	Nexperia	Diode, Switching, 100 V, 0.25 A, SOD-523	SOD-523
D6	1	10V	MMSZ5240BS-7-F	Diodes Inc.	Diode, Zener, 10 V, 200 mW, SOD-323	SOD-323
J1, J2	2		ED555/2DS	On-Shore Technology	Terminal Block, 3.5mm Pitch, 2x1, TH	7.0x8.2x6.5mm
L1	1	3.3uH	EPL2014-332MLB	Coilcraft	Inductor, Shielded, Ferrite, 3.3 uH, 1.1 A, 0.15 ohm, SMD	EPL2014
Q1	1	100V	ZVN3310FTA	Diodes Inc.	MOSFET, N-CH, 100 V, 0.1 A, SOT-23	SOT-23
Q2	1	150V	BSC520N15NS3 G	Infineon Technologies	MOSFET, N-CH, 150 V, 21 A, PG-TDSON-8	PG-TDSON-8
Q3	1	100 V	FCX493TA	Diodes Inc.	Transistor, NPN, 100 V, 1 A, SOT-89	SOT-89
Q4	1	20 V	FMMT718TA	Diodes Inc.	Transistor, PNP, 20 V, 1.5 A, SOT-23	SOT-23
R13	1	0	CRCW04020000Z0ED	Vishay-Dale	RES, 0, 5%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R4	1	4.7	CRCW04024R70JNED	Vishay-Dale	RES, 4.7, 5%, 0.063 W, 0402	0402
R14	1	10	CRCW040210R0FKED	Vishay-Dale	RES, 10.0, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R8, R15	2	1.00k	CRCW04021K00FKED	Vishay-Dale	RES, 1.00 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R16	1	2.00k	CRCW04022K00FKED	Vishay-Dale	RES, 2.00 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R19	1	2.49k	CRCW04022K49FKED	Vishay-Dale	RES, 2.49 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R22	1	3.48k	CRCW04023K48FKED	Vishay-Dale	RES, 3.48 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R17	1	4.99k	CRCW04024K99FKED	Vishay-Dale	RES, 4.99 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R11	1	6.19k	CRCW04026K19FKED	Vishay-Dale	RES, 6.19 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R9	1	10.0k	CRCW040210K0FKED	Vishay-Dale	RES, 10.0 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R21	1	28.0k	CRCW040228K0FKED	Vishay-Dale	RES, 28.0 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R18	1	30.1k	CRCW040230K1FKED	Vishay-Dale	RES, 30.1 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R5, R23	2	100k	CRCW0402100KFKED	Vishay-Dale	RES, 100 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R6	1	150k	CRCW0402150KFKED	Vishay-Dale	RES, 150 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R10	1	0.025	WSL0805R0250FEA	Vishay-Dale	RES, 0.025, 1%, 0.25 W, 0805	0805
R2	1	20	ERJ-6GEYJ200V	Panasonic	RES, 20, 5%, 0.125 W, AEC-Q200 Grade 0, 0805	0805
R1	1	39k	CRCW080539K0JNEA	Vishay-Dale	RES, 39 k, 5%, 0.125 W, AEC-Q200 Grade 0, 0805	0805
R3, R7	2	51	CRCW251251R0JNEG	Vishay-Dale	RES, 51, 5%, 1 W, AEC-Q200 Grade 0, 2512	2512
T1	1		ZF2955-AE	Coilcraft	Flyback Transformer, EP7 8pin SMD 40-57Vin, 750kHz, Output 24V/0.7A, 11.6V/0.02A, Turns Ratio 1:1:0.5	SMT_XFRMR_13MM2_10MM9
U1	1		LM51561DSSR	Texas Instruments	2.2-MHz Wide VIN 65-V Non-synchronous Boost/SEPIC/Flyback Controller with Dual Random Spread Spectrum, DSS0012B (WSON-12)	DSS0012B

Designator	Quantity	Value	PartNumber	Manufacturer	Description	PackageReference
U3	1		TL431LIAIDBZR	Texas Instruments	Programmable Shunt Regulator with Optimized Reference Current, DBZ0003A (SOT-23-3)	DBZ0003A
U4	1		LM4040D50IDBZR	Texas Instruments	Precision Micropower Shunt Voltage Reference, 1% accuracy, 5 V, 15 ppm / degC, 15 mA, -40 to 85 degC, 3-pin SOT-23 (DBZ), Green (RoHS & no Sb/Br)	DBZ0003A
C25	0	0.068uF	885012206070	Wurth Elektronik	CAP, CERM, 0.068 µF, 25 V,+/- 10%, X7R, 0603	0603
R12	0	0	CRCW04020000Z0ED	Vishay-Dale	RES, 0, 5%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
R24	0	1.00k	CRCW04021K00FKED	Vishay-Dale	RES, 1.00 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
Option						
C19	0	100pF	885012005061	Wurth Elektronik	CAP, CERM, 100 pF, 50 V, +/- 5%, C0G/NP0, 0402	0402
C22	1	0.01uF	885012206089	Wurth Elektronik	CAP, CERM, 0.01 µF, 50 V,+/- 10%, X7R, 0603	0603
R20	1	30.1k	CRCW040230K1FKED	Vishay-Dale	RES, 30.1 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
U2B	1		ISOM8110DFG	Texas Instruments	3.75-kVRMS, Single-Channel Opto-Emulator with Transistor Output	SOIC4
Option						
C19	0	100pF	885012005061	Wurth Elektronik	CAP, CERM, 100 pF, 50 V, +/- 5%, C0G/NP0, 0402	0402
C22	0	0.033uF	C1608X7R1H333K080AA	TDK	CAP, CERM, 0.033 uF, 50 V, +/- 10%, X7R, 0603	0603
R20	0	7.50k	CRCW04027K50FKED	Vishay-Dale	RES, 7.50 k, 1%, 0.063 W, AEC-Q200 Grade 0, 0402	0402
U2A	0		TCMT1107	Vishay-Semiconductor	Optocoupler, 3.75 kV, 80-160% CTR, SMT	SOP-4

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Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265